



60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
60V	50mΩ @ V _{GS} = 10V	24A
000	65mΩ @ V _{GS} = 4.5V	21A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine-management systems
- Body control electronics
- DC-DC converters

Features and Benefits

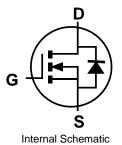
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} Minimizes Power Losses
- Low Q_q Minimizes Switching Losses
- Wettable Flank for Improved Optical Inspections
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMNH6042SPSWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

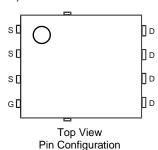
https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)







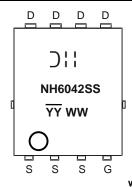
Ordering Information (Note 4)

Part Number	Backago	Packing		
Fait Number	Package	Qty.	Carrier	
DMNH6042SPSWQ-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



);; = Manufacturer's Marking
NH6042SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 23 = 2023)
WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	60	V
Gate-Source Voltage	Vgss	±20	V		
Continuous Drain Current (Note 5) V _{GS} = 10V Steady State		$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	lo	24 17	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	35	Α		
Maximum Continuous Body Diode Forward Current	Is	24	Α		
Avalanche Current (Note 6) L = 10mH	las	3.5	Α		
Avalanche Energy (Note 6) L = 10mH	Eas	65	mJ		

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 7)	PD	1.5	W	
Thermal Resistance, Junction to Ambient (Note 7) Steady State t < 10s		R _{0JA}	98	°C/W
			54	
Total Power Dissipation (Note 8)		PD	2.9	W
Thermal Resistance, Junction to Ambient (Note 8) $ \frac{\text{Steady State}}{\text{t < 10s}} $		Б	51	°C/W
		R _{0JA}	26	
Thermal Resistance, Junction to Case (Note 5)	Rejc	3.5		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage		60	1	_	V	$V_{GS} = 0V, I_{D} = 250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C		_	_	1	μΑ	V _{DS} = 60V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	Vgs(TH)	1.0		3.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	D	_	34	50	mΩ	$V_{GS} = 10V, I_D = 5.1A$	
Static Dialii-Source Oil-Resistance	RDS(ON)	_	45	65	11122	$V_{GS} = 4.5V, I_{D} = 4.4A$	
Diode Forward Voltage	VsD	_	0.8	1.2	V	V _G S = 0V, I _S = 2.6A	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	584	_	pF		
Output Capacitance	Coss	_	83	_	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	24	_	pF	1 = 1.000112	
Gate Resistance	R_g	_	3.8	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	4.2	_	nC		
Total Gate Charge (V _{GS} = 10V)		_	8.8	_	nC	V _{DS} = 44V. I _D = 5.2A	
Gate-Source Charge	Q_{gs}	_	1.8	_	nC	VDS = 44V, ID = 5.2A	
Gate-Drain Charge	Q_{gd}	_	1.8	_	nC	1	
Turn-On Delay Time	tD(ON)	_	3.4	_	ns		
Turn-On Rise Time	t _R	_	1.9	_	ns	$V_{GS} = 10V, V_{DS} = 30V$ $R_g = 6\Omega, I_D = 1A$	
Turn-Off Delay Time	t _{D(OFF)}	_	10.1	_	ns		
Turn-Off Fall Time	tF	_	4.5	_	ns]	
Body Diode Reverse Recovery Time	t _{RR}	_	12.9	_	ns	IF = 2.6A, dI/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Qrr	_	5.4	_	nC	$I_F = 2.6A$, $dI/dt = 100A/\mu s$	

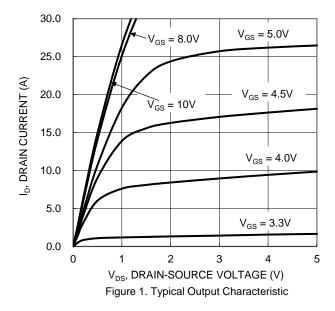
Notes:

- 5. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 6. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
- 7. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 8. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

 9. Short duration pulse test used to minimize self-heating effect.
- 10. Guaranteed by design. Not subject to product testing.







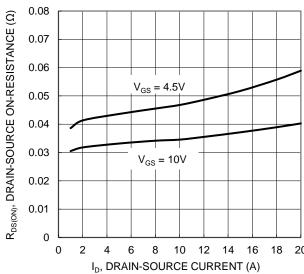


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

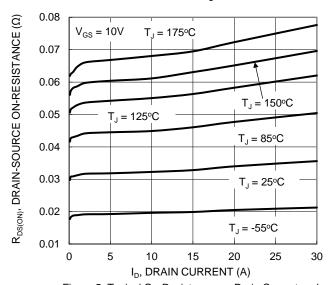


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

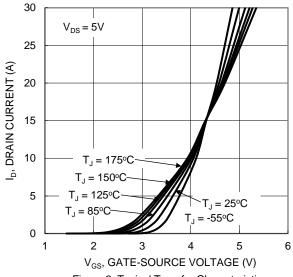


Figure 2. Typical Transfer Characteristic

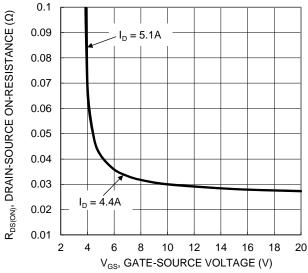


Figure 4. Typical Transfer Characteristic

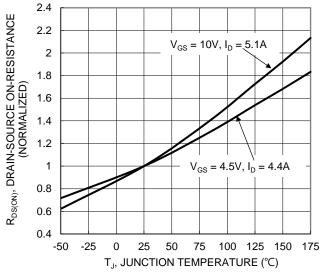
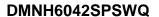


Figure 6. On-Resistance Variation with Temperature





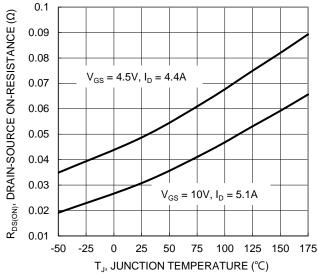
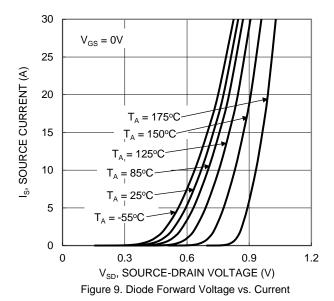


Figure 7. On-Resistance Variation with Temperature



8 6 $V_{GS}(V)$ 4 $V_{DS} = 44V, I_{D} = 5.2A$ 2

 Q_g (nC) Figure 11. Gate Charge

6

8

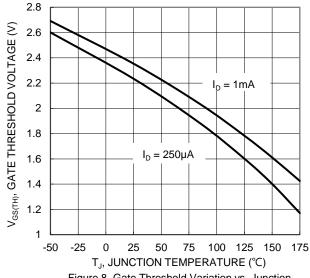
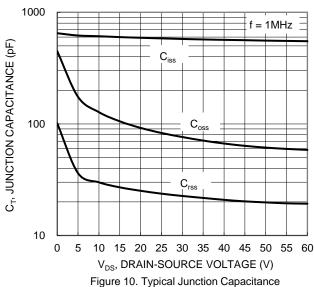
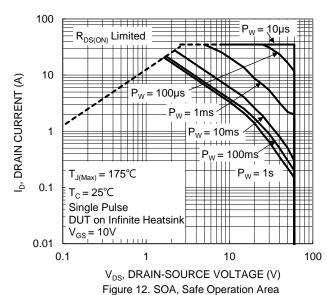


Figure 8. Gate Threshold Variation vs. Junction Temperature





10

2

0

0

10



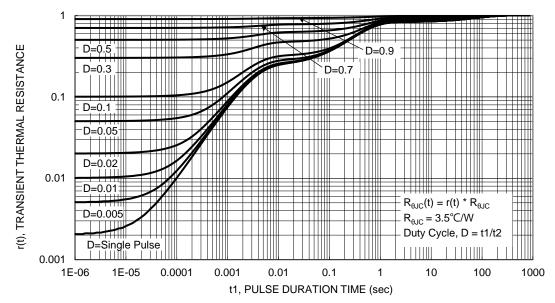


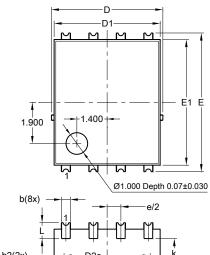
Figure 13. Transient Thermal Resistance

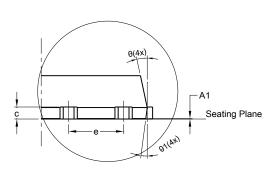


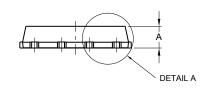
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)







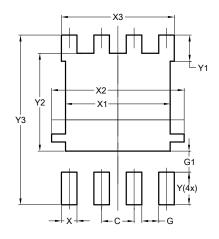
DETAIL A

PowerDI5060-8/SWP						
(Type UX)						
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0	0.05				
b	0.30	0.50	0.41			
b2	0.20	0.35	0.25			
b4	0).25REF				
С	0.230	0.330	0.277			
D	5	.15 BS0)			
D1	4.70	4.70 5.10 4.90				
D2	3.56	3.96	3.76			
D2a	3.78 4.18 3.98					
Е	6.40 BSC					
E1	5.60	6.00	5.80			
E2	3.46	3.86	3.66			
E2a	4.195	4.595	4.395			
е	1.27BSC					
k	1.05					
L	0.635	0.835	0.735			
La	0.635	0.835	0.735			
L1	0.200	0.400	0.300			
L1a	0.050REF					
L4	0.025	0.225	0.125			
M	3.205	4.005	3.605			
θ	10°	12°	11°			
θ1	6°	8°	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)



Dimensions	Value			
2	(in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	5.190			
Х3	4.420			
Y	1.270			
Y1	1.020			
Y2	3.810			
Y3	6.610			



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